NSN 5961-01-309-1315

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-309-1315 **Inclosure Material:** Metal **Overall Length:** 0.150 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 drain to source voltage and 60.0 drain to gate voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current of standard range and 400.00 milliamperes source cutoff current minor **Test Data Document:** 80063-a3012708 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No